

## Excellent Integrated System Limited

Stocking Distributor

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[IXYS Corporation](#)

[MDD56-14N1B](#)

For any questions, you can email us directly:

[sales@integrated-circuit.com](mailto:sales@integrated-circuit.com)

## Standard Rectifier Module

$$V_{RRM} = 2 \times 1400V$$

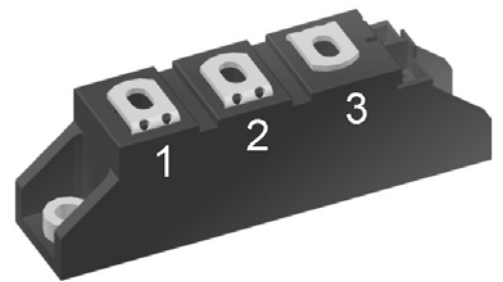
$$I_{FAV} = 71A$$

$$V_F = 1.14V$$


Phase leg

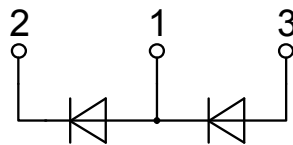
Part number

**MDD56-14N1B**



Backside: isolated

 E72873



### Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

### Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: TO-240AA

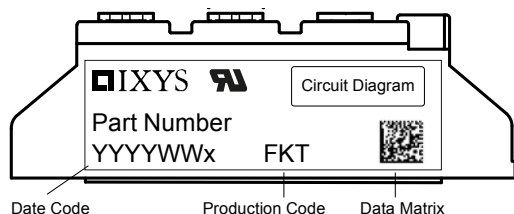
- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

| Rectifier    |  |  |                              | Ratings                      |      |                   |                   |
|--------------|--|--|------------------------------|------------------------------|------|-------------------|-------------------|
| Symbol       | Definition                                   | Conditions                             | min.                         | typ.                         | max. | Unit              |                   |
| $V_{RSM}$    | max. non-repetitive reverse blocking voltage |  |                              |                              | 1500 | V                 |                   |
| $V_{RRM}$    | max. repetitive reverse blocking voltage     |  |                              |                              | 1400 | V                 |                   |
| $I_R$        | reverse current                              | $V_R = 1400\text{ V}$                  | $T_{VJ} = 25^\circ\text{C}$  |                              | 200  | $\mu\text{A}$     |                   |
|              |  | $V_R = 1400\text{ V}$                  | $T_{VJ} = 150^\circ\text{C}$ |                              | 10   | mA                |                   |
| $V_F$        | forward voltage drop                         | $I_F = 100\text{ A}$                   | $T_{VJ} = 25^\circ\text{C}$  |                              | 1.21 | V                 |                   |
|              |  |  |                              |                              | 1.48 | V                 |                   |
|              |  | $I_F = 200\text{ A}$                   | $T_{VJ} = 125^\circ\text{C}$ |                              | 1.14 | V                 |                   |
|              |  |  |                              |                              | 1.45 | V                 |                   |
| $I_{FAV}$    | average forward current                      | $T_C = 100^\circ\text{C}$              | $T_{VJ} = 150^\circ\text{C}$ |                              | 71   | A                 |                   |
| $I_{F(RMS)}$ | RMS forward current                          | 180° sine                              |                              |                              | 150  | A                 |                   |
| $V_{F0}$     | threshold voltage                            | } for power loss calculation only      | $T_{VJ} = 150^\circ\text{C}$ |                              | 0.80 | V                 |                   |
| $r_F$        | slope resistance                             |  |                              |                              | 3    | m $\Omega$        |                   |
| $R_{thJC}$   | thermal resistance junction to case          |  |                              |                              | 0.51 | K/W               |                   |
| $R_{thCH}$   | thermal resistance case to heatsink          |  |                              | 0.20                         |      | K/W               |                   |
| $P_{tot}$    | total power dissipation                      |  | $T_C = 25^\circ\text{C}$     |                              | 245  | W                 |                   |
| $I_{FSM}$    | max. forward surge current                   | t = 10 ms; (50 Hz), sine               | $T_{VJ} = 45^\circ\text{C}$  |                              | 1.40 | kA                |                   |
|              |  |  |                              |                              | 1.51 | kA                |                   |
|              |  | t = 8,3 ms; (60 Hz), sine              | $V_R = 0\text{ V}$           | $T_{VJ} = 150^\circ\text{C}$ |      | 1.19              | kA                |
|              |  |  |                              |                              |      | 1.29              | kA                |
| $I^2t$       | value for fusing                             | t = 10 ms; (50 Hz), sine               | $T_{VJ} = 45^\circ\text{C}$  |                              | 9.80 | kA <sup>2</sup> s |                   |
|              |  |  |                              |                              | 9.49 | kA <sup>2</sup> s |                   |
|              |  | t = 8,3 ms; (60 Hz), sine              | $V_R = 0\text{ V}$           | $T_{VJ} = 150^\circ\text{C}$ |      | 7.08              | kA <sup>2</sup> s |
|              |  |  |                              |                              |      | 6.87              | kA <sup>2</sup> s |
| $C_J$        | junction capacitance                         | $V_R = 400\text{ V}; f = 1\text{ MHz}$ | $T_{VJ} = 25^\circ\text{C}$  |                              | 27   | pF                |                   |



# MDD56-14N1B

| Package TO-240AA |  |                      |                                     | Ratings |      |      |      |
|------------------|--|----------------------|-------------------------------------|---------|------|------|------|
| Symbol           | Definition   | Conditions           |                                     | min.    | typ. | max. | Unit |
| $I_{RMS}$        | RMS current  | per terminal         |                                     |         |      | 200  | A    |
| $T_{VJ}$         | virtual junction temperature                                 |                      |                                     | -40     |      | 150  | °C   |
| $T_{op}$         | operation temperature  |                      |                                     | -40     |      | 125  | °C   |
| $T_{stg}$        | storage temperature  |                      |                                     | -40     |      | 125  | °C   |
| <b>Weight</b>    |  |                      |                                     |         | 90   |      | g    |
| $M_D$            | mounting torque  |                      |                                     | 2.5     |      | 4    | Nm   |
| $M_T$            | terminal torque  |                      |                                     | 2.5     |      | 4    | Nm   |
| $d_{Spp/App}$    | creepage distance on surface   striking distance through air | terminal to terminal | 13.0                                | 9.7     |      |      | mm   |
| $d_{Spb/Apb}$    |  | terminal to backside | 16.0                                | 16.0    |      |      | mm   |
| $V_{ISOL}$       | isolation voltage  | t = 1 second         | 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA | 3600    |      |      | V    |
|                  |  | t = 1 minute         |                                     | 3000    |      |      | V    |

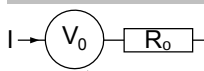


| Ordering | Part Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-------------|--------------------|---------------|----------|----------|
| Standard | MDD56-14N1B | MDD56-14N1B        | Box           | 6        | 458074   |

### Equivalent Circuits for Simulation

\* on die level

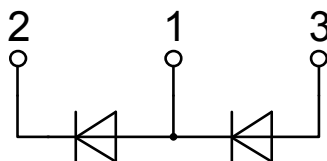
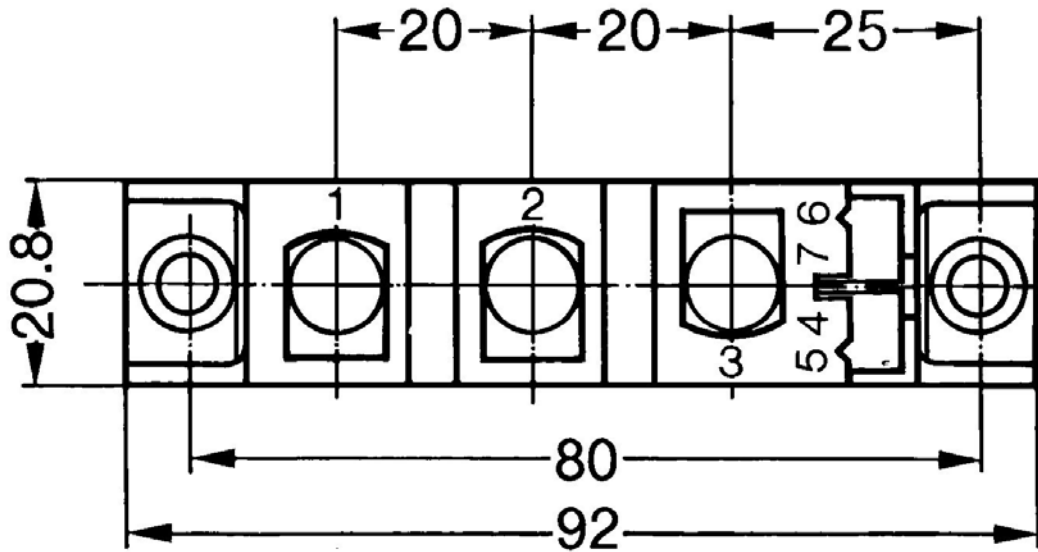
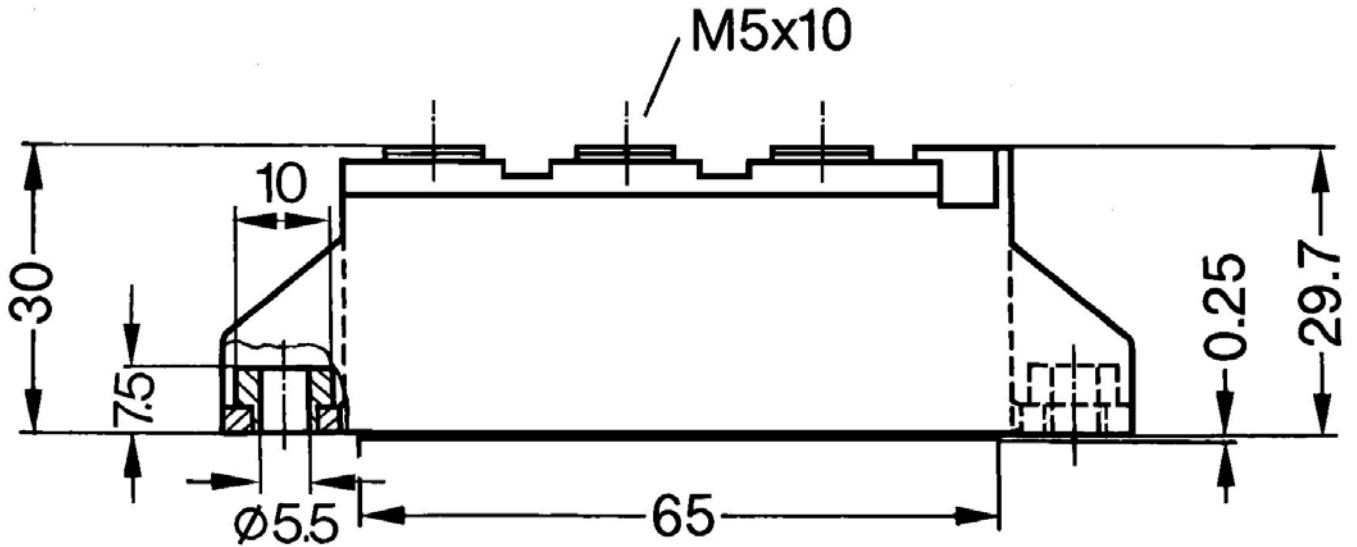
$T_{VJ} = 150^\circ\text{C}$



Rectifier

|             |                    |     |    |
|-------------|--------------------|-----|----|
| $V_{0\max}$ | threshold voltage  | 0.8 | V  |
| $R_{0\max}$ | slope resistance * | 1.8 | mΩ |

Outlines TO-240AA



**Rectifier**

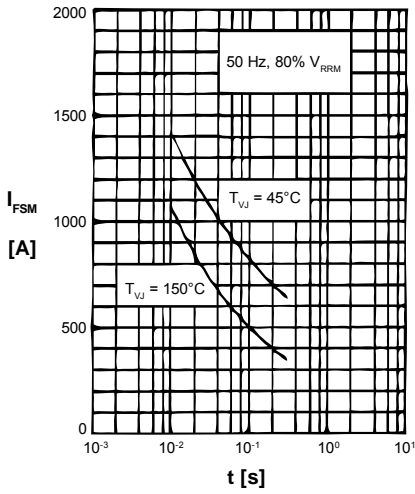


Fig. 1 Surge overload current  
 $I_{TSM}$ ,  $I_{FSM}$ : Crest value,  $t$ : duration

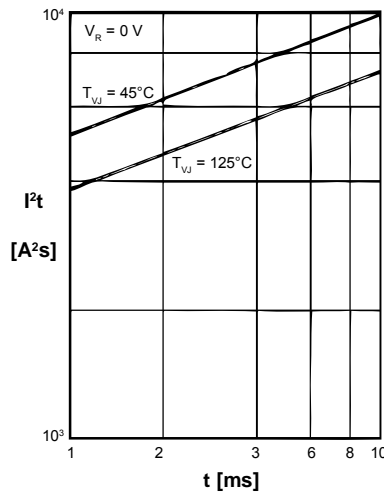


Fig. 2  $I^2t$  versus time (1-10 ms)

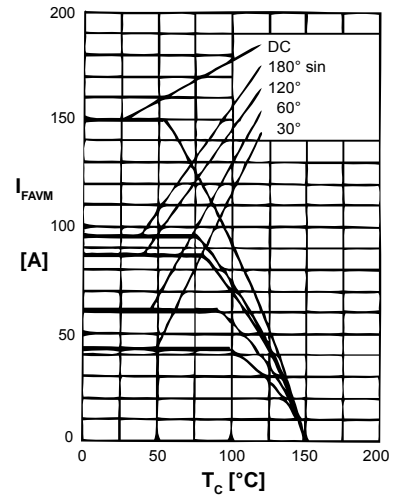


Fig. 3 Maximum forward current at case temperature

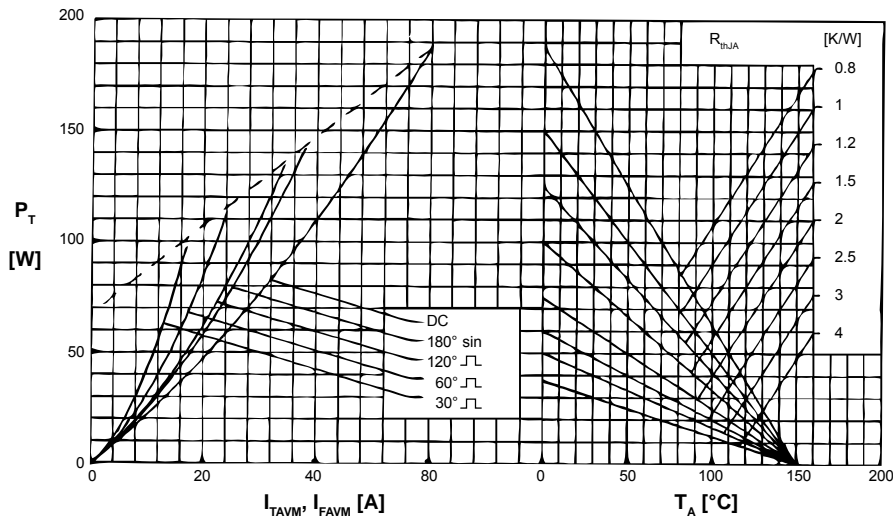


Fig. 4 Power dissipation vs. onstate current and ambient temperature (per diode)

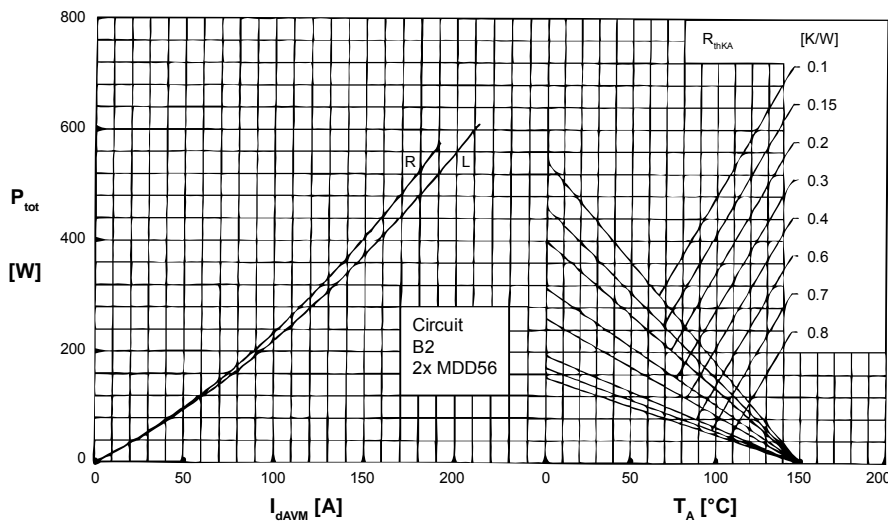


Fig. 6 Single phase rectifier bridge: Power dissipation versus direct output current and ambient temperature; R = resistive load, L = inductive load

**Rectifier**

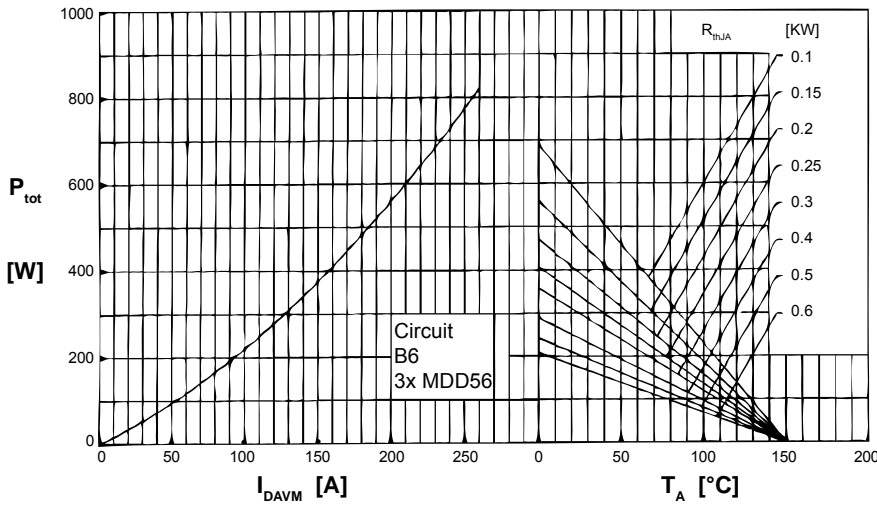


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

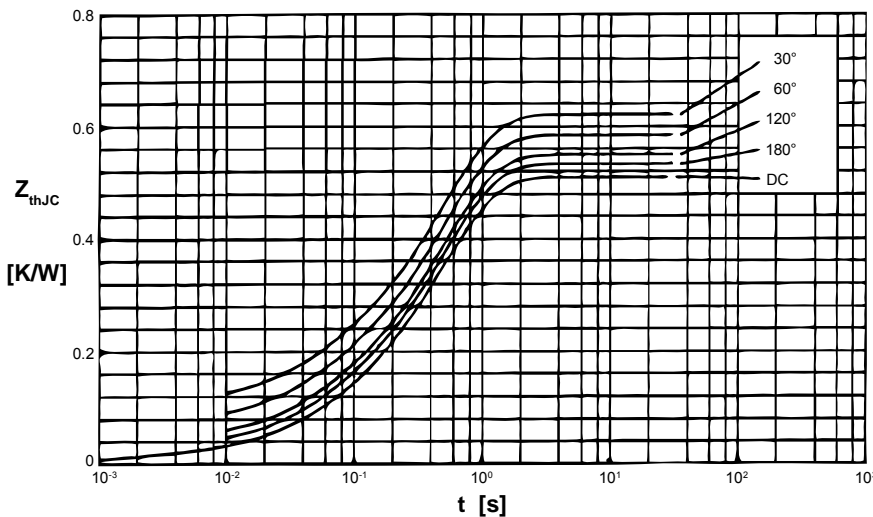


Fig. 7 Transient thermal impedance junction to case (per diode)

$R_{thJC}$  for various conduction angles d:

| d    | $R_{thJC}$ [K/W] |
|------|------------------|
| DC   | 0.51             |
| 180° | 0.53             |
| 120° | 0.55             |
| 60°  | 0.58             |
| 30°  | 0.62             |

Constants for  $Z_{thJC}$  calculation:

| i | $R_{thi}$ [K/W] | $t_i$ [s] |
|---|-----------------|-----------|
| 1 | 0.013           | 0.0015    |
| 2 | 0.055           | 0.0450    |
| 3 | 0.442           | 0.4850    |

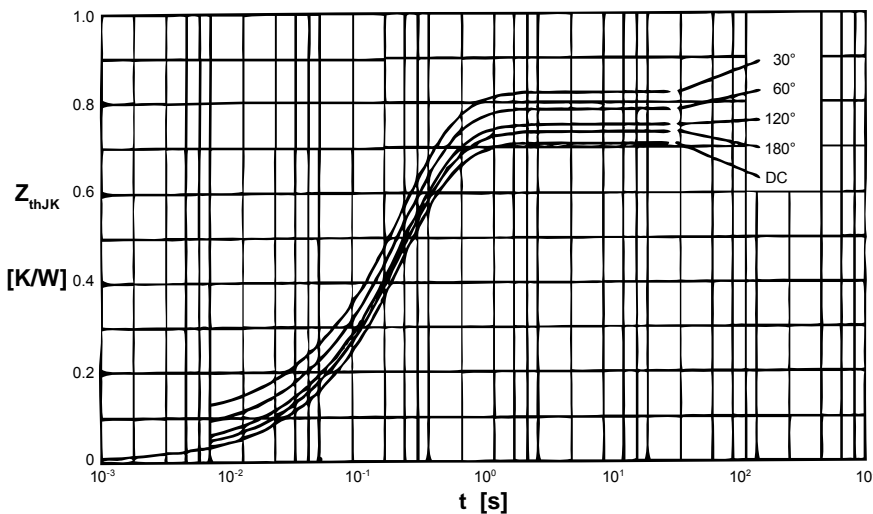


Fig. 8 Transient thermal impedance junction to heatsink (per thyristor)

$R_{thJK}$  for various conduction angles d:

| d    | $R_{thJK}$ [K/W] |
|------|------------------|
| DC   | 0.71             |
| 180° | 0.73             |
| 120° | 0.75             |
| 60°  | 0.78             |
| 30°  | 0.82             |

Constants for  $Z_{thJK}$  calculation:

| i | $R_{thi}$ [K/W] | $t_i$ [s] |
|---|-----------------|-----------|
| 1 | 0.013           | 0.0015    |
| 2 | 0.055           | 0.0450    |
| 3 | 0.442           | 0.4850    |
| 4 | 0.200           | 1.2500    |